

# LMV931-N/LMV931-N-Q1/LMV932-N/LMV932-N-Q1/LMV934-N/LMV934-N-Q1

## Single/Dual/Quad 1.8V, RRIO Operational Amplifiers

Check for Samples: [LMV931-N](#), [LMV931-N-Q1](#), [LMV932-N](#), [LMV932-N-Q1](#), [LMV934-N](#), [LMV934-N-Q1](#)

### FEATURES

(Typical 1.8V Supply Values; Unless Otherwise Noted)

- **LMV931-N/LMV932-N/LMV934-N are Available in Automotive AEC-Q100 Grade 1 Versions**
- **Guaranteed 1.8V, 2.7V and 5V Specifications**
- **Output Swing**
  - w/600Ω Load 80mV from Rail
  - w/2kΩ Load 30mV from Rail
- **V<sub>CM</sub> 200mV Beyond Rails**
- **Supply Current (Per Channel) 100μA**
- **Gain Bandwidth Product 1.4MHz**
- **Maximum V<sub>OS</sub> 4.0mV**
- **Ultra Tiny Packages**
- **Temperature Range –40°C to 125°C**

### APPLICATIONS

- **Consumer Communication**
- **Consumer Computing**
- **PDA's**
- **Audio Pre-amp**
- **Portable/Battery-powered Electronic Equipment**
- **Supply Current Monitoring**
- **Battery Monitoring**

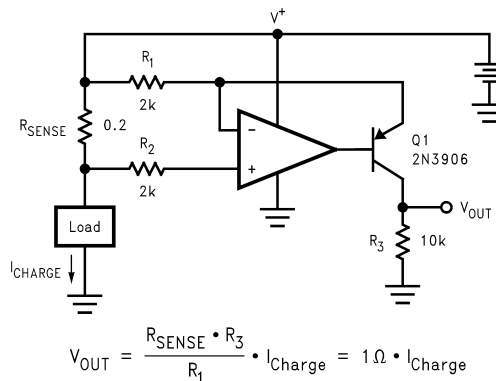
### DESCRIPTION

The LMV931-N/LMV932-N/LMV934-N are low voltage, low power operational amplifiers. LMV931-N/LMV932-N/LMV934-N operate from +1.8V to +5.5V supply voltages and have rail-to-rail input and output. LMV931-N/LMV932-N/LMV934-N input common mode voltage extends 200mV beyond the supplies which enables user enhanced functionality beyond the supply voltage range. The output can swing rail-to-rail unloaded and within 105mV from the rail with 600Ω load at 1.8V supply. The LMV931-N/LMV932-N/LMV934-N are optimized to work at 1.8V which make them ideal for portable two-cell battery powered systems and single cell Li-Ion systems.

LMV931-N/LMV932-N/LMV934-N exhibit excellent speed-power ratio, achieving 1.4MHz gain bandwidth product at 1.8V supply voltage with very low supply current. The LMV931-N/LMV932-N/LMV934-N are capable of driving a 600Ω load and up to 1000pF capacitive load with minimal ringing. LMV931-N/LMV932-N/LMV934-N have a high DC gain of 101dB, making them suitable for low frequency applications.

The single LMV931-N is offered in space saving 5-Pin SC70 and SOT-23 packages. The dual LMV932-N are in 8-Pin VSSOP and SOIC packages and the quad LMV934-N are in 14-Pin TSSOP and SOIC packages. These small packages are ideal solutions for area constrained PC boards and portable electronics such as cellular phones and PDA's.

### Typical Application



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings<sup>(1)(2)</sup>

ESD Tolerance <sup>(3)</sup>	Charged Device Model	750V
	Machine Model	200V
	Human Body Model	2000V
Supply Voltage ( $V^+ - V^-$ )		6V
Differential Input Voltage		$\pm$ Supply Voltage
Voltage at Input/Output Pins		$V^+ + 0.3V$ , $V^- - 0.3V$
Storage Temperature Range		-65°C to 150°C
Junction Temperature <sup>(4)</sup>		150°C
For soldering specifications:		
See product folder at <a href="http://www.ti.com">www.ti.com</a> and <a href="http://www.ti.com/lit/SNOA549">http://www.ti.com/lit/SNOA549</a>		

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office / Distributors for availability and specifications.
- (3) Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).
- (4) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $\theta_{JA}$  and  $T_A$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC Board.

## Operating Ratings<sup>(1)</sup>

Supply Voltage Range		1.8V to 5.5V
Temperature Range		-40°C to 125°C
Thermal Resistance ( $\theta_{JA}$ )	5-Pin SC70	414°C/W
	5-Pin SOT-23	265°C/W
	8-Pin VSSOP	235°C/W
	8-Pin SOIC	175°C/W
	14-Pin TSSOP	155°C/W
	14-Pin SOIC	127°C/W

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

## 1.8V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 1.8V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{ M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See<sup>(1)</sup>

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
$V_{OS}$	Input Offset Voltage	LMV931-N (Single)		1	<b>4</b> <b>6</b>	mV
		LMV932-N (Dual) LMV934-N (Quad)		1	<b>5.5</b> <b>7.5</b>	mV

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) All limits are guaranteed by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

## 1.8V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 1.8\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{ M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See<sup>(1)</sup>

Symbol	Parameter	Condition		Min (2)	Typ (3)	Max (2)	Units
TCV <sub>OS</sub>	Input Offset Voltage Average Drift				5.5		μV/°C
I <sub>B</sub>	Input Bias Current				15	35 50	nA
I <sub>OS</sub>	Input Offset Current				13	25 40	nA
I <sub>S</sub>	Supply Current (per channel)				103	185 205	μA
CMRR	Common Mode Rejection Ratio	LMV931-N, 0 ≤ V <sub>CM</sub> ≤ 0.6V 1.4V ≤ V <sub>CM</sub> ≤ 1.8V <sup>(4)</sup>		60 55	78		dB
		LMV932-N and LMV934-N 0 ≤ V <sub>CM</sub> ≤ 0.6V 1.4V ≤ V <sub>CM</sub> ≤ 1.8V <sup>(4)</sup>		55 50	76		
		−0.2V ≤ V <sub>CM</sub> ≤ 0V 1.8V ≤ V <sub>CM</sub> ≤ 2.0V		50	72		
PSRR	Power Supply Rejection Ratio	1.8V ≤ V <sup>+</sup> ≤ 5V		75 70	100		dB
CMVR	Input Common-Mode Voltage Range	For CMRR Range ≥ 50dB	T <sub>A</sub> = 25°C	V <sup>−</sup> −0.2	−0.2 to 2.1	V <sup>+</sup> +0.2	V
			T <sub>A</sub> −40°C to 85°C	V <sup>−</sup>		V <sup>+</sup>	
			T <sub>A</sub> = 125°C	V <sup>−</sup> +0.2		V <sup>+</sup> −0.2	
A <sub>V</sub>	Large Signal Voltage Gain LMV931-N (Single)	R <sub>L</sub> = 600Ω to 0.9V, V <sub>O</sub> = 0.2V to 1.6V, V <sub>CM</sub> = 0.5V		77 73	101		dB
		R <sub>L</sub> = 2kΩ to 0.9V, V <sub>O</sub> = 0.2V to 1.6V, V <sub>CM</sub> = 0.5V		80 75	105		
	Large Signal Voltage Gain LMV932-N (Dual) LMV934-N (Quad)	R <sub>L</sub> = 600Ω to 0.9V, V <sub>O</sub> = 0.2V to 1.6V, V <sub>CM</sub> = 0.5V		75 72	90		dB
		R <sub>L</sub> = 2kΩ to 0.9V, V <sub>O</sub> = 0.2V to 1.6V, V <sub>CM</sub> = 0.5V		78 75	100		
V <sub>O</sub>	Output Swing	R <sub>L</sub> = 600Ω to 0.9V V <sub>IN</sub> = ±100mV		1.65 1.63	1.72		V
					0.077	0.105 0.120	
		R <sub>L</sub> = 2kΩ to 0.9V V <sub>IN</sub> = ±100mV		1.75 1.74	1.77		
					0.024	0.035 0.04	
I <sub>O</sub>	Output Short Circuit Current <sup>(5)</sup>	Sourcing, V <sub>O</sub> = 0V V <sub>IN</sub> = 100mV		4 3.3	8		mA
		Sinking, V <sub>O</sub> = 1.8V V <sub>IN</sub> = −100mV		7 5	9		

(4) For guaranteed temperature ranges, see Input Common-Mode Voltage Range specifications.

(5) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of  $150^\circ\text{C}$ . Output currents in excess of  $45\text{mA}$  over long term may adversely affect reliability.

## 1.8V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 1.8\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{ M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See <sup>(1)</sup>

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
SR	Slew Rate	See <sup>(4)</sup>		0.35		V/ $\mu\text{s}$
GBW	Gain-Bandwidth Product			1.4		MHz
$\Phi_m$	Phase Margin			67		deg
$G_m$	Gain Margin			7		dB
$e_n$	Input-Referred Voltage Noise	$f = 10\text{ kHz}$ , $V_{\text{CM}} = 0.5\text{V}$		60		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-Referred Current Noise	$f = 10\text{ kHz}$		0.08		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$ , $A_V = +1$ $R_L = 600\Omega$ , $V_{\text{IN}} = 1\text{ V}_{\text{PP}}$		0.023		%
	Amp-to-Amp Isolation	See <sup>(5)</sup>		123		dB

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) All limits are guaranteed by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- (4) Connected as voltage follower with input step from  $V^-$  to  $V^+$ . Number specified is the slower of the positive and negative slew rates.
- (5) Input referred,  $R_L = 100\text{k}\Omega$  connected to  $V^+/2$ . Each amp excited in turn with  $1\text{ kHz}$  to produce  $V_O = 3\text{V}_{\text{PP}}$  (For Supply Voltages  $< 3\text{V}$ ,  $V_O = V^+$ ).

## 2.7V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{ M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See <sup>(1)</sup>

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
$V_{\text{OS}}$	Input Offset Voltage	LMV931-N (Single)		1	4 <b>6</b>	mV
		LMV932-N (Dual) LMV934-N (Quad)		1	5.5 <b>7.5</b>	mV
$\text{TCV}_{\text{OS}}$	Input Offset Voltage Average Drift			5.5		$\mu\text{V}/^\circ\text{C}$
$I_B$	Input Bias Current			15	35 <b>50</b>	nA
$I_{\text{OS}}$	Input Offset Current			8	25 <b>40</b>	nA
$I_S$	Supply Current (per channel)			105	190 <b>210</b>	$\mu\text{A}$

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) All limits are guaranteed by testing or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

## 2.7V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{ M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See <sup>(1)</sup>

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
CMRR	Common Mode Rejection Ratio	LMV931-N, $0 \leq V_{CM} \leq 1.5\text{V}$ $2.3\text{V} \leq V_{CM} \leq 2.7\text{V}^{(4)}$	60 <b>55</b>	81		dB
		LMV932-N and LMV934-N $0 \leq V_{CM} \leq 1.5\text{V}$ $2.3\text{V} \leq V_{CM} \leq 2.7\text{V}^{(4)}$	55 <b>50</b>	80		
		$-0.2\text{V} \leq V_{CM} \leq 0\text{V}$ $2.7\text{V} \leq V_{CM} \leq 2.9\text{V}$	50	74		
PSRR	Power Supply Rejection Ratio	$1.8\text{V} \leq V^+ \leq 5\text{V}$ $V_{CM} = 0.5\text{V}$	75 <b>70</b>	100		dB
$V_{CM}$	Input Common-Mode Voltage Range	For CMRR Range $\geq 50\text{dB}$	$T_A = 25^\circ\text{C}$ $V^- - 0.2$	$-0.2$ to $3.0$	$V^+ + 0.2$	V
			$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$ $V^-$		$V^+$	
			$T_A = 125^\circ\text{C}$ $V^- + 0.2$		$V^+ - 0.2$	
$A_V$	Large Signal Voltage Gain LMV931-N (Single)	$R_L = 600\Omega$ to $1.35\text{V}$ , $V_O = 0.2\text{V}$ to $2.5\text{V}$	87 <b>86</b>	104		dB
		$R_L = 2\text{k}\Omega$ to $1.35\text{V}$ , $V_O = 0.2\text{V}$ to $2.5\text{V}$	92 <b>91</b>	110		
	Large Signal Voltage Gain LMV932-N (Dual) LMV934-N (Quad)	$R_L = 600\Omega$ to $1.35\text{V}$ , $V_O = 0.2\text{V}$ to $2.5\text{V}$	78 <b>75</b>	90		dB
		$R_L = 2\text{k}\Omega$ to $1.35\text{V}$ , $V_O = 0.2\text{V}$ to $2.5\text{V}$	81 <b>78</b>	100		
$V_O$	Output Swing	$R_L = 600\Omega$ to $1.35\text{V}$ $V_{IN} = \pm 100\text{mV}$	2.55 <b>2.53</b>	2.62		V
				0.083	0.110 <b>0.130</b>	
		$R_L = 2\text{k}\Omega$ to $1.35\text{V}$ $V_{IN} = \pm 100\text{mV}$	2.65 <b>2.64</b>	2.675		
				0.025	0.04 <b>0.045</b>	
$I_O$	Output Short Circuit Current <sup>(5)</sup>	Sourcing, $V_O = 0\text{V}$ $V_{IN} = 100\text{mV}$	20 <b>15</b>	30		mA
		Sinking, $V_O = 0\text{V}$ $V_{IN} = -100\text{mV}$	18 <b>12</b>	25		

(4) For guaranteed temperature ranges, see Input Common-Mode Voltage Range specifications.

(5) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of  $150^\circ\text{C}$ . Output currents in excess of  $45\text{mA}$  over long term may adversely affect reliability.

## 2.7V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = 1.0\text{V}$ ,  $V_O = 1.35\text{V}$  and  $R_L > 1\text{ M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See <sup>(1)</sup>

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
SR	Slew Rate	See <sup>(4)</sup>		0.4		V/ $\mu\text{s}$

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

(2) All limits are guaranteed by testing or statistical analysis.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

(4) Connected as voltage follower with input step from  $V^-$  to  $V^+$ . Number specified is the slower of the positive and negative slew rates.

## 2.7V AC Electrical Characteristics (continued)

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = 1.0\text{V}$ ,  $V_O = 1.35\text{V}$  and  $R_L > 1\text{M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See <sup>(1)</sup>

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
GBW	Gain-Bandwidth Product			1.4		MHz
$\Phi_m$	Phase Margin			70		deg
$G_m$	Gain Margin			7.5		dB
$e_n$	Input-Referred Voltage Noise	$f = 10\text{ kHz}$ , $V_{CM} = 0.5\text{V}$		57		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-Referred Current Noise	$f = 10\text{ kHz}$		0.08		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total Harmonic Distortion	$f = 1\text{kHz}$ , $A_V = +1$ $R_L = 600\Omega$ , $V_{IN} = 1\text{V}_{PP}$		0.022		%
	Amp-to-Amp Isolation	See <sup>(5)</sup>		123		dB

(5) Input referred,  $R_L = 100\text{k}\Omega$  connected to  $V^+/2$ . Each amp excited in turn with  $1\text{kHz}$  to produce  $V_O = 3V_{PP}$  (For Supply Voltages  $< 3\text{V}$ ,  $V_O = V^+$ ).

## 5V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See <sup>(1)</sup>

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
$V_{OS}$	Input Offset Voltage	LMV931-N (Single)		1	4 <b>6</b>	mV
		LMV932-N (Dual) LMV934-N (Quad)		1	5.5 <b>7.5</b>	mV
$TCV_{OS}$	Input Offset Voltage Average Drift			5.5		$\mu\text{V}/^\circ\text{C}$
$I_B$	Input Bias Current			14	35 <b>50</b>	nA
$I_{OS}$	Input Offset Current			9	25 <b>40</b>	nA
$I_S$	Supply Current (per channel)			116	210 <b>230</b>	$\mu\text{A}$
CMRR	Common Mode Rejection Ratio	$0 \leq V_{CM} \leq 3.8\text{V}$ $4.6\text{V} \leq V_{CM} \leq 5.0\text{V}$ <sup>(4)</sup>	60 <b>55</b>	86		dB
		$-0.2\text{V} \leq V_{CM} \leq 0\text{V}$ $5.0\text{V} \leq V_{CM} \leq 5.2\text{V}$	50	78		
PSRR	Power Supply Rejection Ratio	$1.8\text{V} \leq V^+ \leq 5\text{V}$ $V_{CM} = 0.5\text{V}$	75 70	100		dB
CMVR	Input Common-Mode Voltage Range	For CMRR Range $\geq 50\text{dB}$		$-0.2$ to $5.3$	$V^+ + 0.2$	V
		$T_A = 25^\circ\text{C}$	$V^- - 0.2$		$V^+$	
		$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$	$V^-$			
		$T_A = 125^\circ\text{C}$	$V^- + 0.3$		$V^+ - 0.3$	

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

(2) All limits are guaranteed by testing or statistical analysis.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

(4) For guaranteed temperature ranges, see Input Common-Mode Voltage Range specifications.

## 5V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1\text{M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See<sup>(1)</sup>

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
$A_V$	Large Signal Voltage Gain LMV931-N (Single)	$R_L = 600\Omega$ to $2.5\text{V}$ , $V_O = 0.2\text{V}$ to $4.8\text{V}$	88 <b>87</b>	102		dB
		$R_L = 2\text{k}\Omega$ to $2.5\text{V}$ , $V_O = 0.2\text{V}$ to $4.8\text{V}$	94 <b>93</b>	113		
	Large Signal Voltage Gain LMV932-N (Dual) LMV934-N (Quad)	$R_L = 600\Omega$ to $2.5\text{V}$ , $V_O = 0.2\text{V}$ to $4.8\text{V}$	81 <b>78</b>	90		dB
		$R_L = 2\text{k}\Omega$ to $2.5\text{V}$ , $V_O = 0.2\text{V}$ to $4.8\text{V}$	85 <b>82</b>	100		
$V_O$	Output Swing	$R_L = 600\Omega$ to $2.5\text{V}$ $V_{IN} = \pm 100\text{mV}$	4.855 4.835	4.890		V
				0.120	0.160 <b>0.180</b>	
		$R_L = 2\text{k}\Omega$ to $2.5\text{V}$ $V_{IN} = \pm 100\text{mV}$	4.945 <b>4.935</b>	4.967		
				0.037	0.065 <b>0.075</b>	
$I_O$	Output Short Circuit Current <sup>(5)</sup>	LMV931-N, Sourcing, $V_O = 0\text{V}$ $V_{IN} = 100\text{mV}$	80 <b>68</b>	100		mA
		Sinking, $V_O = 5\text{V}$ $V_{IN} = -100\text{mV}$	58 <b>45</b>	65		

(5) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of  $150^\circ\text{C}$ . Output currents in excess of  $45\text{mA}$  over long term may adversely affect reliability.

## 5V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ ,  $V_O = 2.5\text{V}$  and  $R_L > 1\text{M}\Omega$ .

**Boldface** limits apply at the temperature extremes. See<sup>(1)</sup>

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
SR	Slew Rate	See <sup>(4)</sup>		0.42		V/ $\mu\text{s}$
GBW	Gain-Bandwidth Product			1.5		MHz
$\Phi_m$	Phase Margin			71		deg
$G_m$	Gain Margin			8		dB
$e_n$	Input-Referred Voltage Noise	$f = 10\text{kHz}$ , $V_{CM} = 1\text{V}$		50		nV/ $\sqrt{\text{Hz}}$
$i_n$	Input-Referred Current Noise	$f = 10\text{kHz}$		0.08		pA/ $\sqrt{\text{Hz}}$
THD	Total Harmonic Distortion	$f = 1\text{kHz}$ , $A_V = +1$ $R_L = 600\Omega$ , $V_O = 1\text{V}_{PP}$		0.022		%
	Amp-to-Amp Isolation	See <sup>(5)</sup>		123		dB

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . See Applications section for information of temperature derating of the device. Absolute Maximum Ratings indicated junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

(2) All limits are guaranteed by testing or statistical analysis.

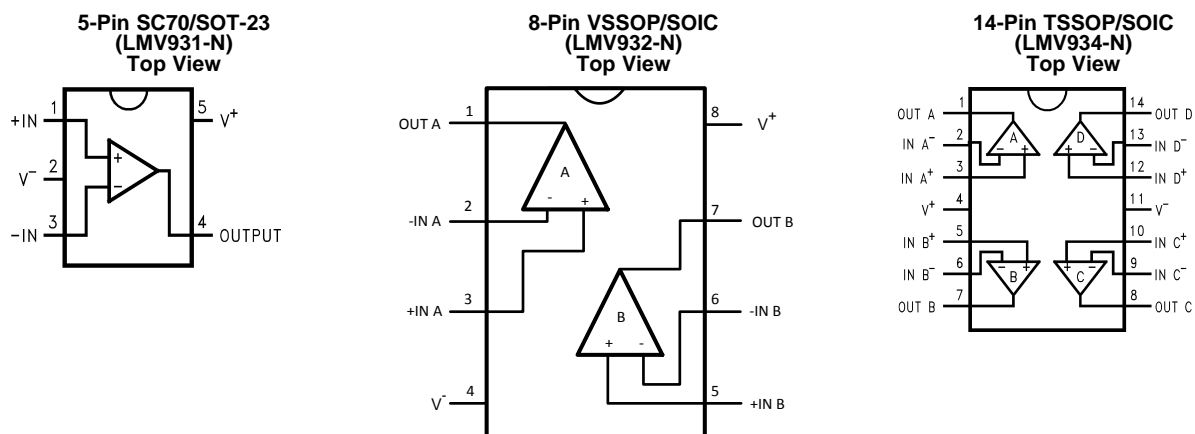
(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

(4) Connected as voltage follower with input step from  $V^-$  to  $V^+$ . Number specified is the slower of the positive and negative slew rates.

(5) Input referred,  $R_L = 100\text{k}\Omega$  connected to  $V^+/2$ . Each amp excited in turn with  $1\text{kHz}$  to produce  $V_O = 3V_{PP}$  (For Supply Voltages  $< 3\text{V}$ ,  $V_O = V^+$ ).



## CONNECTION DIAGRAMS



Devices with an asterisk (\*) are future products. Please contact the factory for availability.

Automotive Grade (Q) product incorporates enhanced manufacturing and support processes for the automotive market, including defect detection methodologies. Reliability qualification is compliant with the requirements and temperature grades defined in the AEC Q100 standard. Automotive Grade products are identified with the letter Q. Fully compliant PPAP documentation is available. For more information go to [http://www.ti.com/lscs/ti/apps/automotive/end\\_equipment.page](http://www.ti.com/lscs/ti/apps/automotive/end_equipment.page).



## Typical Performance Characteristics

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

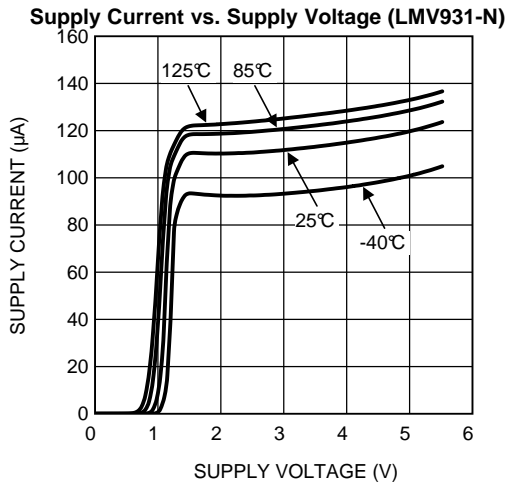


Figure 1.

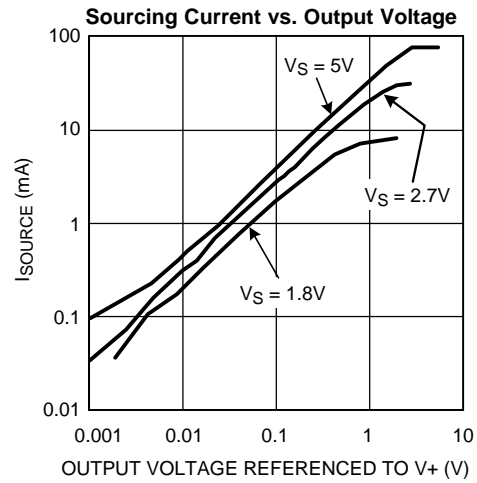


Figure 2.

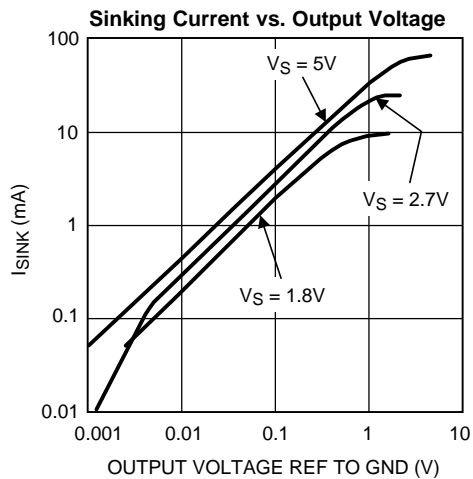


Figure 3.

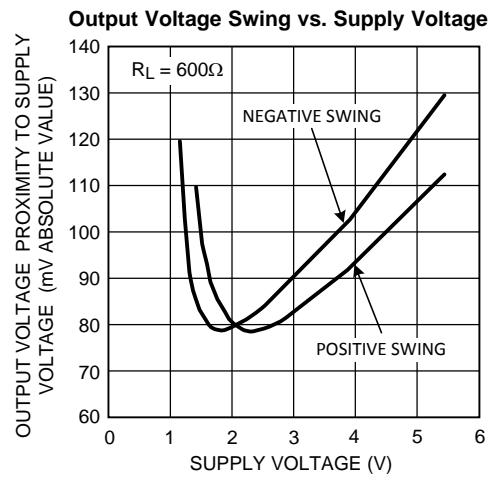


Figure 4.

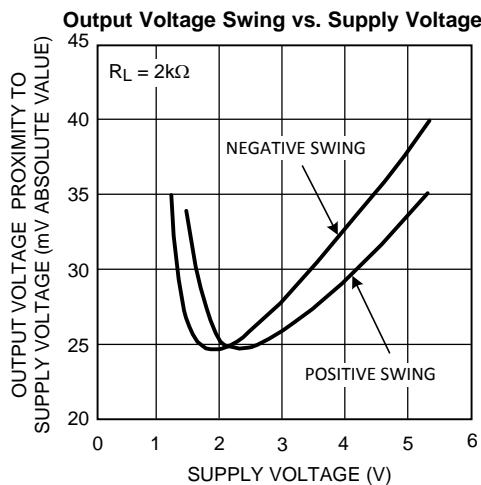


Figure 5.

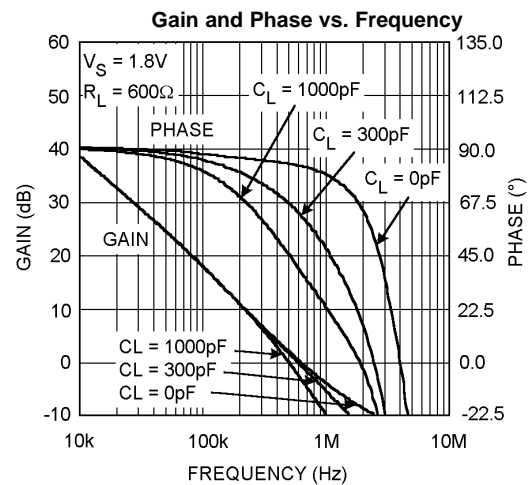


Figure 6.

## Typical Performance Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

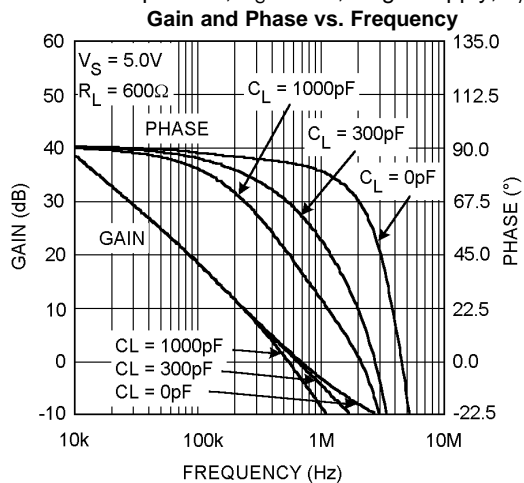


Figure 7.

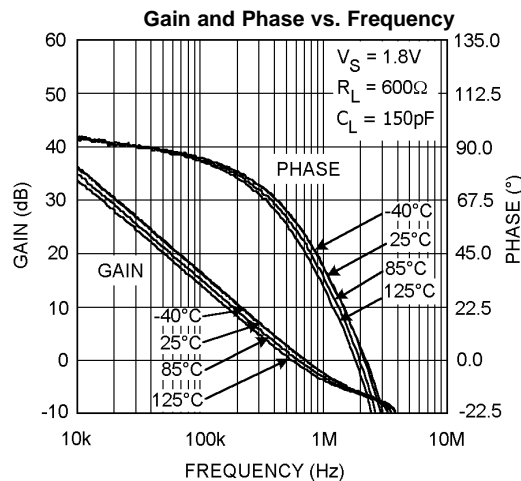


Figure 8.

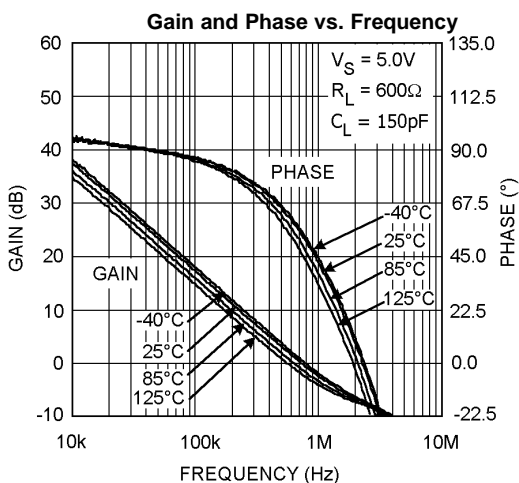


Figure 9.

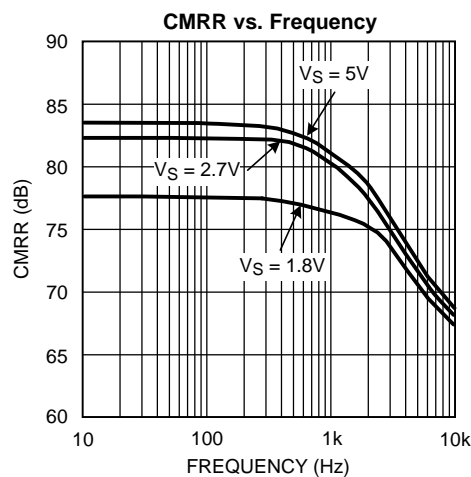


Figure 10.

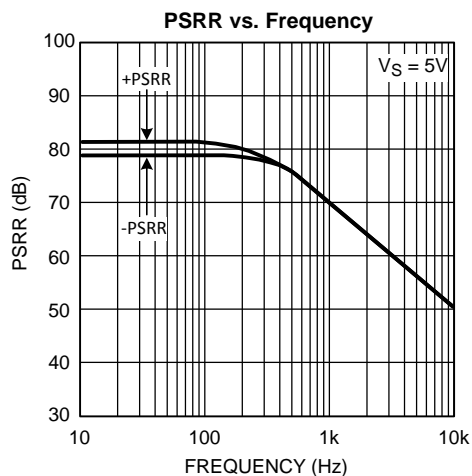


Figure 11.

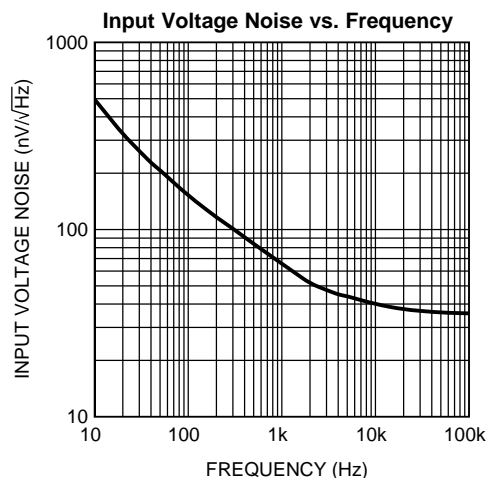


Figure 12.

## Typical Performance Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

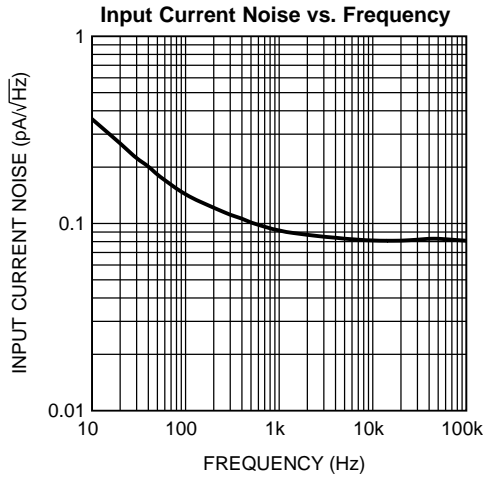


Figure 13.

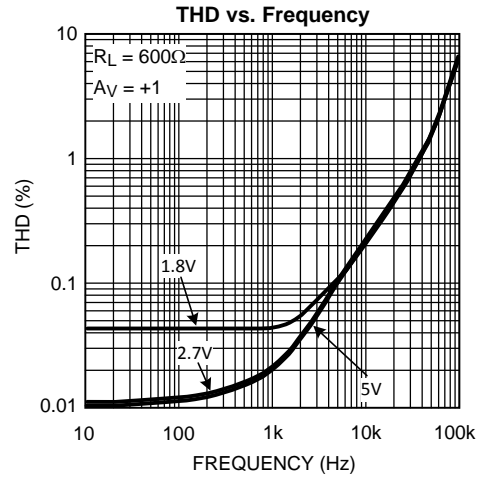


Figure 14.

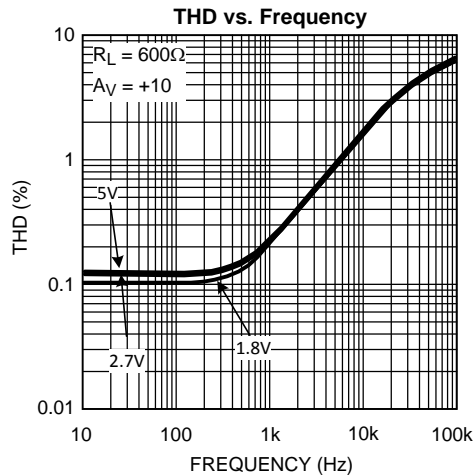


Figure 15.

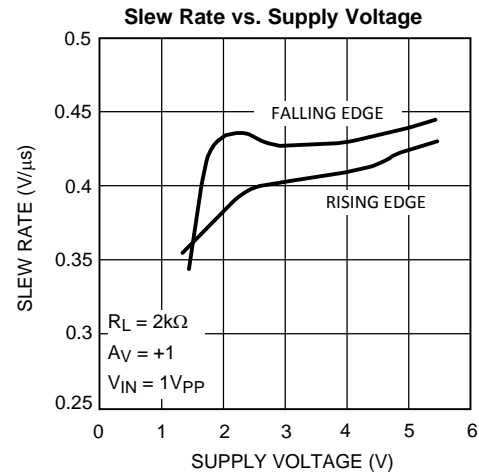


Figure 16.

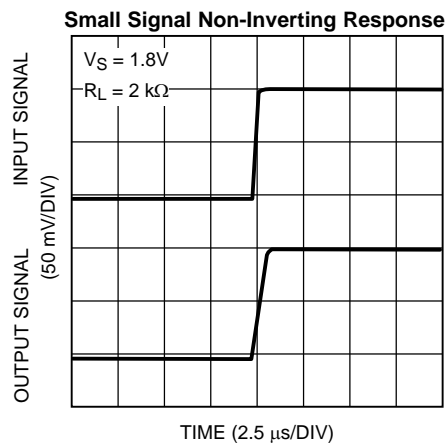


Figure 17.

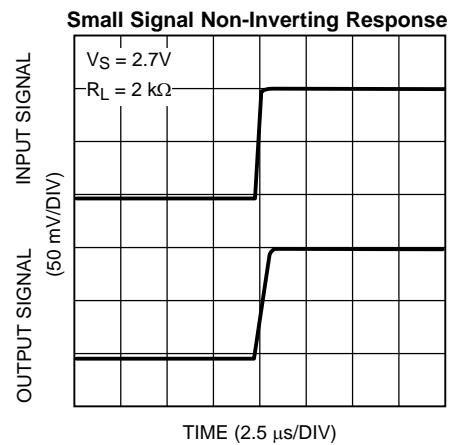


Figure 18.

## Typical Performance Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

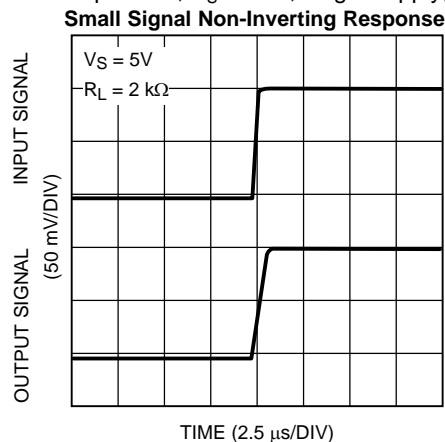


Figure 19.

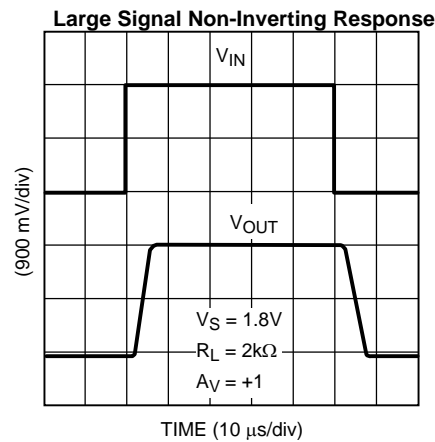


Figure 20.

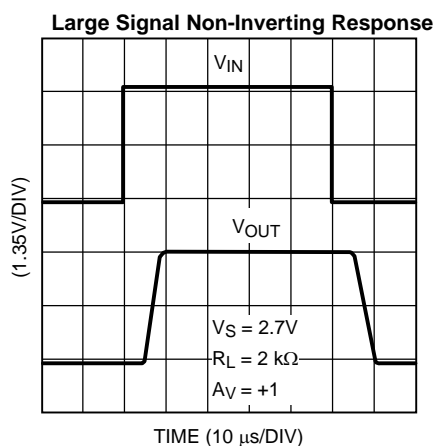


Figure 21.

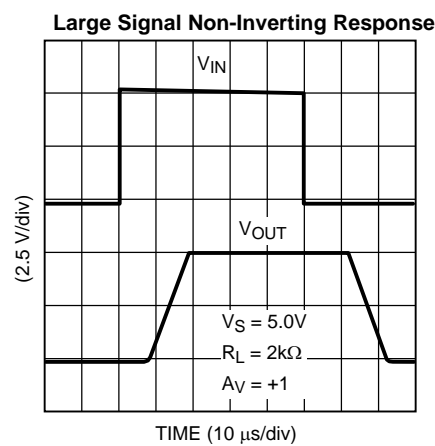


Figure 22.

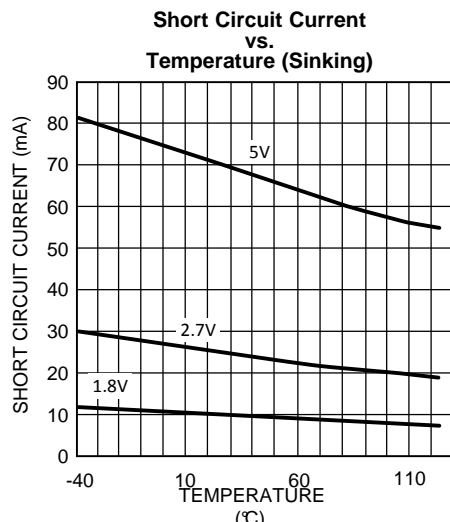


Figure 23.

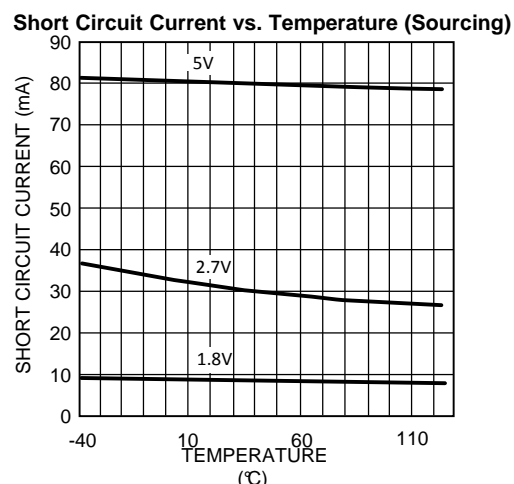


Figure 24.

## Typical Performance Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

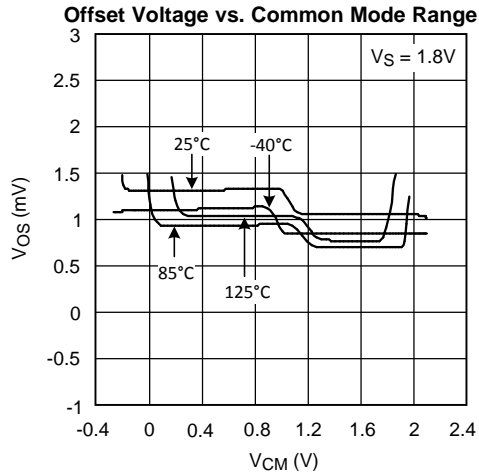


Figure 25.

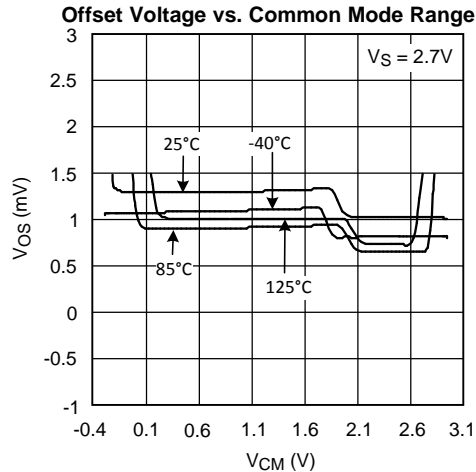


Figure 26.

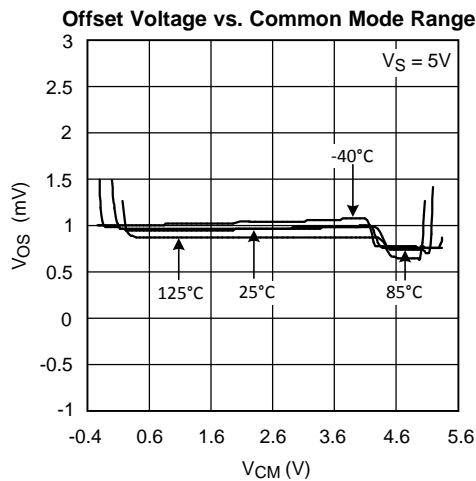


Figure 27.

## APPLICATION NOTE

### INPUT AND OUTPUT STAGE

The rail-to-rail input stage of this family provides more flexibility for the designer. The LMV931-N/LMV932-N/LMV934-N use a complimentary PNP and NPN input stage in which the PNP stage senses common mode voltage near  $V^-$  and the NPN stage senses common mode voltage near  $V^+$ . The transition from the PNP stage to NPN stage occurs 1V below  $V^+$ . Since both input stages have their own offset voltage, the offset of the amplifier becomes a function of the input common mode voltage and has a crossover point at 1V below  $V^+$ .

This  $V_{OS}$  crossover point can create problems for both DC and AC coupled signals if proper care is not taken. Large input signals that include the  $V_{OS}$  crossover point will cause distortion in the output signal. One way to avoid such distortion is to keep the signal away from the crossover. For example, in a unity gain buffer configuration and with  $V_S = 5V$ , a 5V peak-to-peak signal will contain input-crossover distortion while a 3V peak-to-peak signal centered at 1.5V will not contain input-crossover distortion as it avoids the crossover point. Another way to avoid large signal distortion is to use a gain of  $-1$  circuit which avoids any voltage excursions at the input terminals of the amplifier. In that circuit, the common mode DC voltage can be set at a level away from the  $V_{OS}$  cross-over point. For small signals, this transition in  $V_{OS}$  shows up as a  $V_{CM}$  dependent spurious signal in series with the input signal and can effectively degrade small signal parameters such as gain and common mode rejection ratio. To resolve this problem, the small signal should be placed such that it avoids the  $V_{OS}$  crossover point. In addition to the rail-to-rail performance, the output stage can provide enough output current to drive 600 $\Omega$  loads. Because of the high current capability, care should be taken not to exceed the 150°C maximum junction temperature specification.

### INPUT BIAS CURRENT CONSIDERATION

The LMV931-N/LMV932-N/LMV934-N family has a complementary bipolar input stage. The typical input bias current ( $I_B$ ) is 15nA. The input bias current can develop a significant offset voltage. This offset is primarily due to  $I_B$  flowing through the negative feedback resistor,  $R_F$ . For example, if  $I_B$  is 50nA and  $R_F$  is 100k $\Omega$ , then an offset voltage of 5mV will develop ( $V_{OS} = I_B \times R_F$ ). Using a compensation resistor ( $R_C$ ), as shown in Figure 28, cancels this effect. But the input offset current ( $I_{OS}$ ) will still contribute to an offset voltage in the same manner.

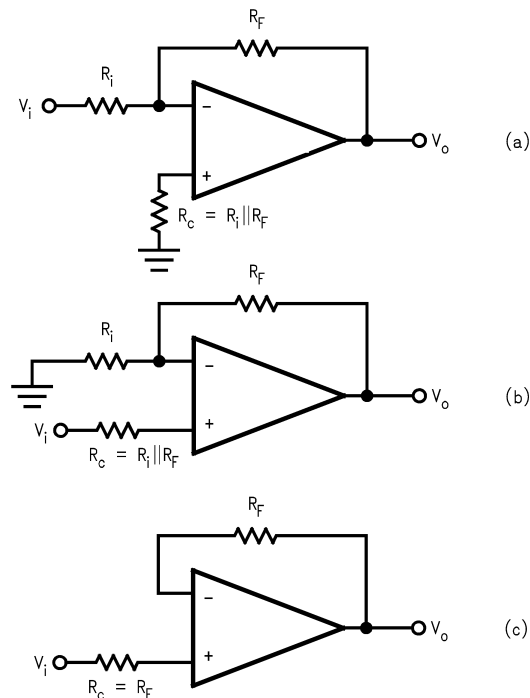


Figure 28. Canceling the Offset Voltage due to Input Bias Current

## TYPICAL APPLICATIONS

### HIGH SIDE CURRENT SENSING

The high side current sensing circuit (Figure 29) is commonly used in a battery charger to monitor charging current to prevent over charging. A sense resistor  $R_{\text{SENSE}}$  is connected to the battery directly. This system requires an op amp with rail-to-rail input. The LMV931-N/LMV932-N/LMV934-N are ideal for this application because its common mode input range goes up to the rail.

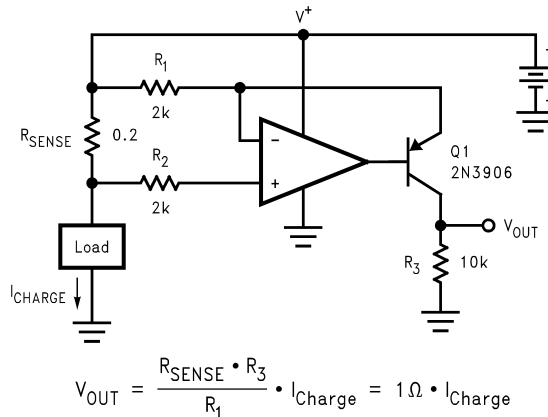


Figure 29. High Side Current Sensing

### HALF-WAVE RECTIFIER WITH RAIL-TO-GROUND OUTPUT SWING

Since the LMV931-N/LMV932-N/LMV934-N input common mode range includes both positive and negative supply rails and the output can also swing to either supply, achieving half-wave rectifier functions in either direction is an easy task. All that is needed are two external resistors; there is no need for diodes or matched resistors. The half wave rectifier can have either positive or negative going outputs, depending on the way the circuit is arranged.

In Figure 30 the circuit is referenced to ground, while in Figure 31 the circuit is biased to the positive supply. These configurations implement the half wave rectifier since the LMV931-N/LMV932-N/LMV934-N can not respond to one-half of the incoming waveform. It can not respond to one-half of the incoming because the amplifier can not swing the output beyond either rail therefore the output disengages during this half cycle. During the other half cycle, however, the amplifier achieves a half wave that can have a peak equal to the total supply voltage.  $R_i$  should be large enough not to load the LMV931-N/LMV932-N/LMV934-N.

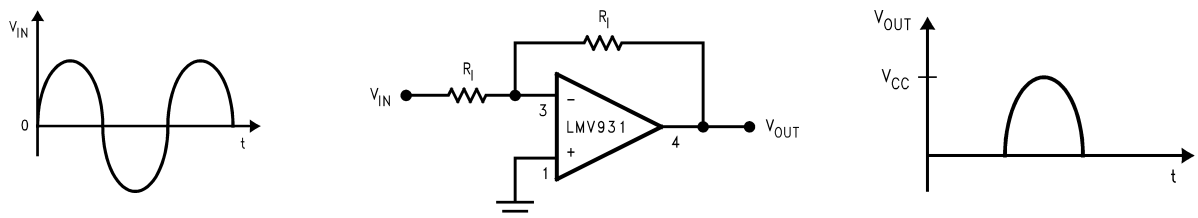
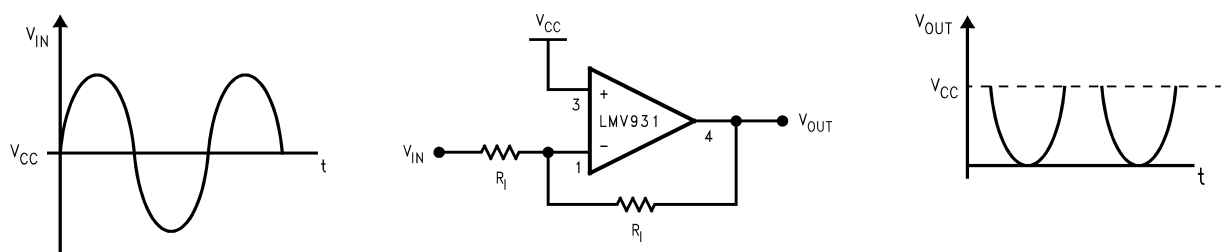


Figure 30. Half-Wave Rectifier with Rail-To-Ground Output Swing Referenced to Ground





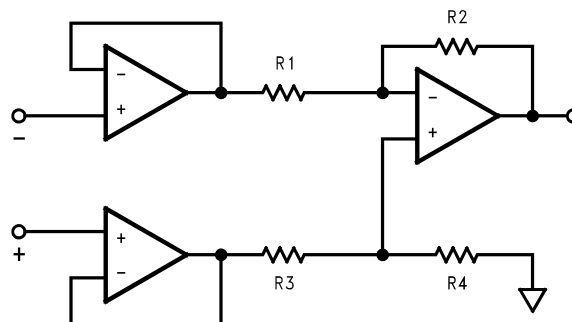
**Figure 31. Half-Wave Rectifier with Negative-Going Output Referenced to  $V_{CC}$**

### INSTRUMENTATION AMPLIFIER WITH RAIL-TO-RAIL INPUT AND OUTPUT

Some manufactures make a non-“rail-to-rail”-op amp rail-to-rail by using a resistive divider on the inputs. The resistors divide the input voltage to get a rail-to-rail input range. The problem with this method is that it also divides the signal, so in order to get the obtained gain, the amplifier must have a higher closed loop gain. This raises the noise and drift by the internal gain factor and lowers the input impedance. Any mismatch in these precision resistors reduces the CMRR as well. The LMV931-N/LMV932-N/LMV934-N is rail-to-rail and therefore doesn't have these disadvantages.

Using three of the LMV931-N/LMV932-N/LMV934-N amplifiers, an instrumentation amplifier with rail-to-rail inputs and outputs can be made as shown in [Figure 32](#).

In this example, amplifiers on the left side act as buffers to the differential stage. These buffers assure that the input impedance is very high and require no precision matched resistors in the input stage. They also assure that the difference amp is driven from a voltage source. This is necessary to maintain the CMRR set by the matching  $R_1$ - $R_2$  with  $R_3$ - $R_4$ . The gain is set by the ratio of  $R_2/R_1$  and  $R_3$  should equal  $R_1$  and  $R_4$  equal  $R_2$ . With both rail-to-rail input and output ranges, the input and output are only limited by the supply voltages. Remember that even with rail-to-rail outputs, the output can not swing past the supplies so the combined common mode voltages plus the signal should not be greater than the supplies or limiting will occur. For additional applications, see Texas Instruments application notes AN-29 ([SNOA625](#)), AN-31 ([SNLA140](#)), AN-71 ([SNOA652](#)), and AN-127 ([SNVA516](#)).



**Figure 32. Rail-to-rail Instrumentation Amplifier**

Product Folder Links: [LMV931-N](#) [LMV931-N-Q1](#) [LMV932-N](#) [LMV932-N-Q1](#) [LMV934-N](#) [LMV934-N-Q1](#)

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMV931MF	ACTIVE	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 125	A79A	<a href="#">Samples</a>
LMV931MF/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	A79A	<a href="#">Samples</a>
LMV931MFX	ACTIVE	SOT-23	DBV	5	3000	TBD	Call TI	Call TI	-40 to 125	A79A	<a href="#">Samples</a>
LMV931MFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	A79A	<a href="#">Samples</a>
LMV931MG	ACTIVE	SC70	DCK	5	1000	TBD	Call TI	Call TI	-40 to 125	A74	<a href="#">Samples</a>
LMV931MG/NOPB	ACTIVE	SC70	DCK	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	A74	<a href="#">Samples</a>
LMV931MGX	ACTIVE	SC70	DCK	5	3000	TBD	Call TI	Call TI	-40 to 125	A74	<a href="#">Samples</a>
LMV931MGX/NOPB	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	A74	<a href="#">Samples</a>
LMV932MA	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 125	LMV9 32MA	<a href="#">Samples</a>
LMV932MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV9 32MA	<a href="#">Samples</a>
LMV932MAX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 125	LMV9 32MA	<a href="#">Samples</a>
LMV932MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV9 32MA	<a href="#">Samples</a>
LMV932MM	ACTIVE	VSSOP	DGK	8	1000	TBD	Call TI	Call TI	-40 to 125	A86A	<a href="#">Samples</a>
LMV932MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	A86A	<a href="#">Samples</a>
LMV932MMX	ACTIVE	VSSOP	DGK	8	3500	TBD	Call TI	Call TI	-40 to 125	A86A	<a href="#">Samples</a>
LMV932MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	A86A	<a href="#">Samples</a>
LMV934MA	ACTIVE	SOIC	D	14	55	TBD	Call TI	Call TI	-40 to 125	LMV934MA	<a href="#">Samples</a>
LMV934MA/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV934MA	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMV934MAX	ACTIVE	SOIC	D	14	2500	TBD	Call TI	Call TI	-40 to 125	LMV934MA	<a href="#">Samples</a>
LMV934MAX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV934MA	<a href="#">Samples</a>
LMV934MT/NOPB	ACTIVE	TSSOP	PW	14	94	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV93 4MT	<a href="#">Samples</a>
LMV934MTX	ACTIVE	TSSOP	PW	14	2500	TBD	Call TI	Call TI	-40 to 125	LMV93 4MT	<a href="#">Samples</a>
LMV934MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV93 4MT	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

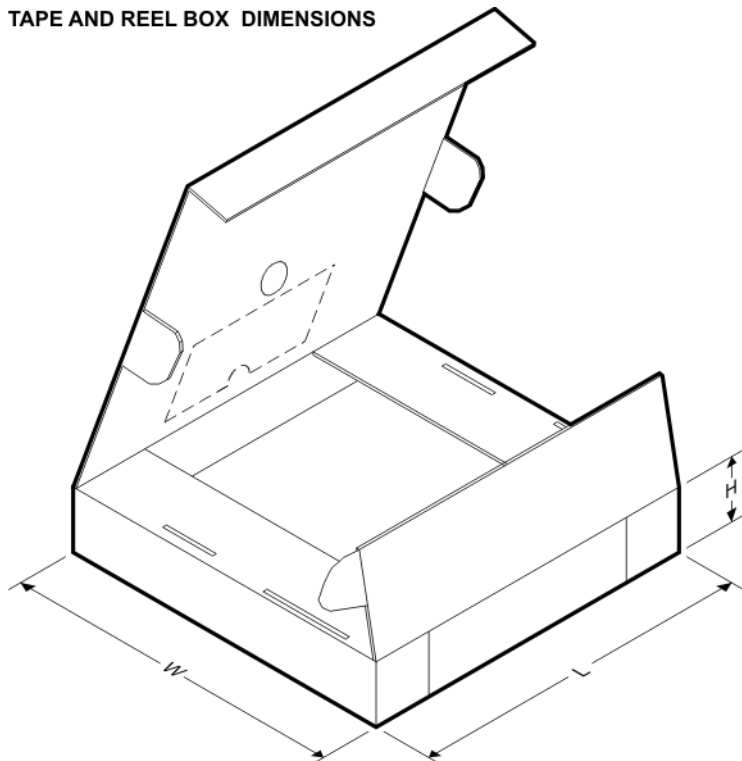


**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV931MF	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV931MF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV931MFX	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV931MFX/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV931MG	SC70	DCK	5	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV931MG/NOPB	SC70	DCK	5	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV931MGX	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV931MGX/NOPB	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV932MAX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV932MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV932MM	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV932MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV932MMX	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV932MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV934MAX	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMV934MAX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMV934MTX	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1
LMV934MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



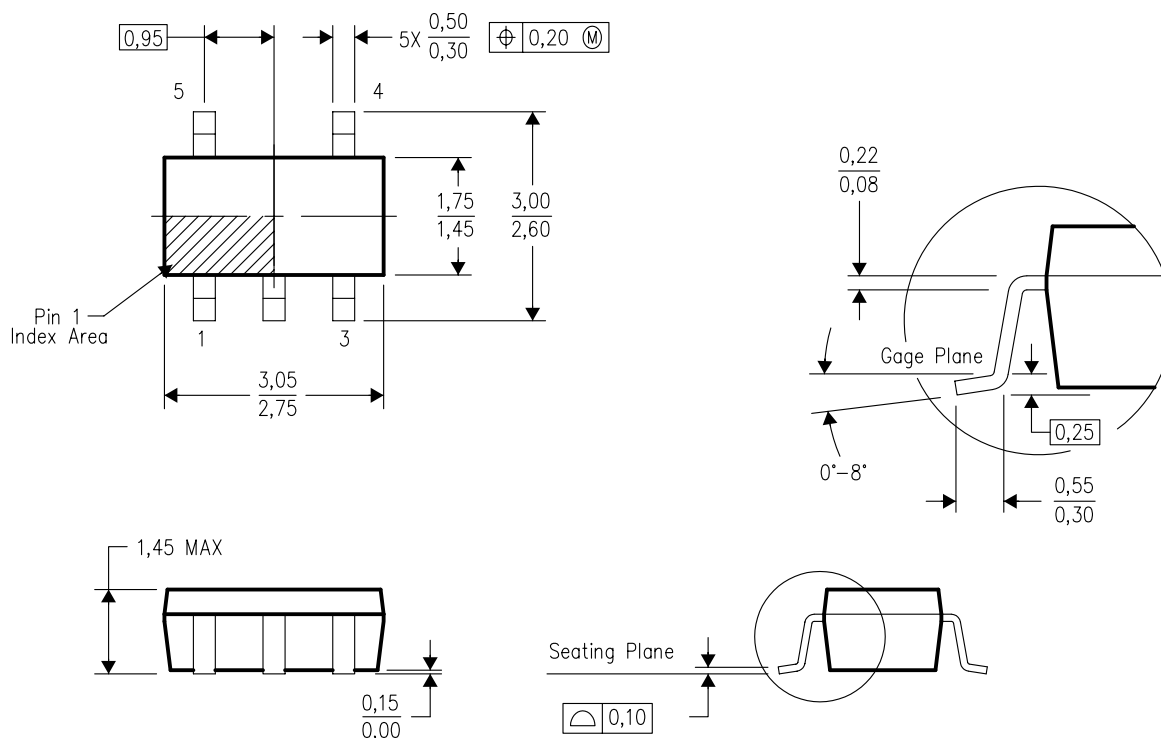
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV931MF	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV931MF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV931MFX	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV931MFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV931MG	SC70	DCK	5	1000	210.0	185.0	35.0
LMV931MG/NOPB	SC70	DCK	5	1000	210.0	185.0	35.0
LMV931MGX	SC70	DCK	5	3000	210.0	185.0	35.0
LMV931MGX/NOPB	SC70	DCK	5	3000	210.0	185.0	35.0
LMV932MAX	SOIC	D	8	2500	367.0	367.0	35.0
LMV932MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMV932MM	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV932MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV932MMX	VSSOP	DGK	8	3500	367.0	367.0	35.0
LMV932MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LMV934MAX	SOIC	D	14	2500	349.0	337.0	45.0
LMV934MAX/NOPB	SOIC	D	14	2500	349.0	337.0	45.0
LMV934MTX	TSSOP	PW	14	2500	367.0	367.0	35.0
LMV934MTX/NOPB	TSSOP	PW	14	2500	367.0	367.0	35.0



## DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



4073253-4/K 03/2006

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.

DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

## DCK (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



4093553-3/G 01/2007

- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - Falls within JEDEC MO-203 variation AA.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



## NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE

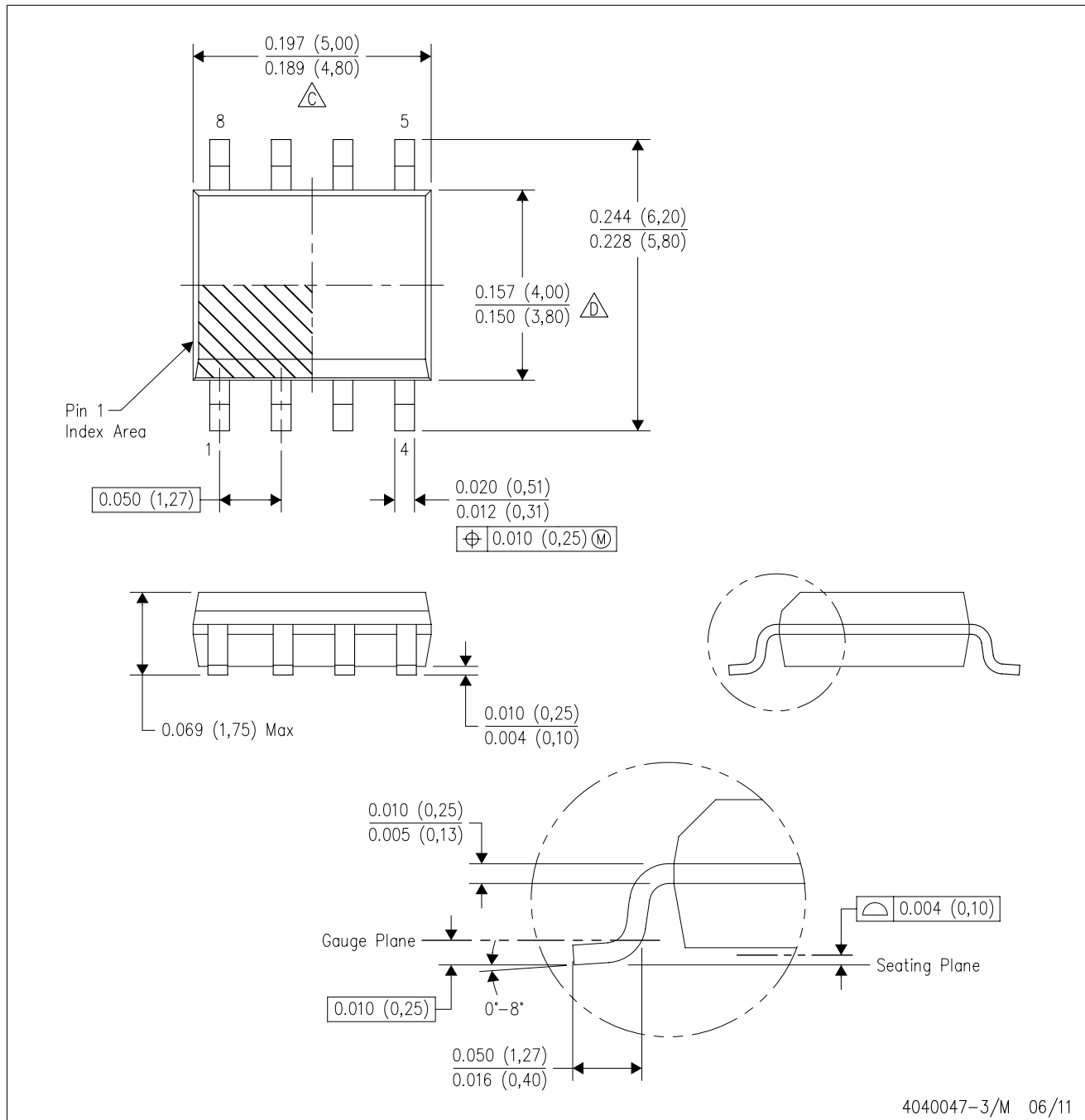


4040064-3/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - $\triangle D$  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AA.



## IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

### Products

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>
OMAP Applications Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>
Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>

### Applications

Automotive and Transportation	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
Communications and Telecom	<a href="http://www.ti.com/communications">www.ti.com/communications</a>
Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
Consumer Electronics	<a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>
Energy and Lighting	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
Space, Avionics and Defense	<a href="http://www.ti.com/space-avionics-defense">www.ti.com/space-avionics-defense</a>
Video and Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>

### TI E2E Community

[e2e.ti.com](http://e2e.ti.com)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.